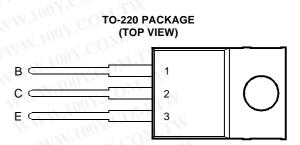
W.100Y.COM. TIPL760B, TIPL760C NPN SILICON POWER TRANSISTORS

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- **Rugged Triple-Diffused Planar Construction**
- **4 A Continuous Collector Current**
- **Operating Characteristics Fully Guaranteed** at 100°C
- **1200 Volt Blocking Capability**
- 75 W at 25°C Case Temperature



Pin 2 is in electrical contact with the mounting base.

MDTRACA

WWW.100 absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	W.	SYMBOL	VALUE	UNI
Collector-base voltage (I _E = 0)	TIPL760B TIPL760C	V _{CBO}	1100 1200	V
Collector-emitter voltage (V _{BE} = 0)	TIPL760B TIPL760C	V _{CES}	1100 1200	V
Collector-emitter voltage (I _B = 0)	TIPL760B TIPL760C	V _{CEO}	500 550	V
Emitter-base voltage		V _{EBO}	10	V
Continuous collector current	N N	I _C	4	Α
Peak collector current (see Note 1)	-1	I _{CM}	8	Α
Continuous device dissipation at (or below) 25°C case temperature		P _{tot}	75	W
Operating junction temperature range	W	VINT ₁	-65 to +150	°C
Storage temperature range			-65 to +150	°C

NOTE 1: This value applies for $t_p \le 10$ ms, duty cycle $\le 2\%$. WWW.100Y.COM.TW WWW.100Y.

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PRODUCT INFORMATION

Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.



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electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER	A COMP	TEST C	ONDITIONS		MIN	TYP	MAX	UNIT
V _{CEO(sus)}	Collector-emitter sustaining voltage	I _C = 10 mA	L = 25 mH	(see Note 2)	TIPL760B TIPL760C	500 550			V
Own	WW W	V _{CE} = 1100 V	$V_{BE} = 0$	NW.	TIPL760B	N.		50	
-M.	Collector-emitter	V _{CE} = 1200 V	$V_{BE} = 0$		TIPL760C	N		50	
ICES	cut-off current	V _{CE} = 1100 V	$V_{BE} = 0$	$T_{C} = 100^{\circ}C$	TIPL760B	1.7.		200	μA
		V _{CE} = 1200 V	$V_{BE} = 0$	T _C = 100°C	TIPL760C	WT .		200	
100	Collector cut-off	$V_{CE} = 500 V$	I _B = 0	W	TIPL760B		N	50	
ICEO	current	$V_{CE} = 550 V$	$I_{B} = 0$		TIPL760C	ON.		50	μA
I _{EBO}	Emitter cut-off current	V _{EB} = 10 V	$I_{\rm C} = 0$		WW.100Y.C	COM'I	N.	1	mA
h _{FE}	Forward current transfer ratio	V _{CE} = 5 V	$I_{\rm C} = 0.5 {\rm A}$	(see Notes 3 an	nd 4)	20	WT	60	
Too	Collector-emitter	I _B = 0.4 A	I _C = 2 A	Nr.	WWW.	COr	1	1.0	
V _{CE(sat)}	saturation voltage	I _B = 0.6 A	I _C = 3 A	(see Notes 3 an	nd 4)	CO.	$M_{1,1}$	2.5	V
	Saturation voltage	I _B = 0.6 A	I _C = 3 A	$T_{C} = 100^{\circ}C$		NY.C	TA	5.0	
1.100	Base-emitter saturation voltage	I _B = 0.4 A	$I_{\rm C} = 2 {\rm A}$		WWW.	V.C	J	1.2	
V _{BE(sat)}		I _B = 0.6 A	I _C = 3 A	(see Notes 3 an	nd 4)		·WO	1.4	V
N.V.		I _B = 0.6 A	I _C = 3 A	$T_{C} = 100^{\circ}C$		1001.		1.3	
ft	Current gain bandwidth product	V _{CE} = 10 V	I _C = 0.5 A	f = 1 MHz	WWW	×.100X	12	I.TW	MHz
C _{ob}	Output capacitance	V _{CB} = 20 V	$I_{\rm E} = 0$	f = 0.1 MHz	W.Y.	001 -	110	TIM	pF

3. These parameters must be measured using pulse techniques, t_p = 300 $\mu s,$ duty cycle $\leq 2\%.$

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts. WW.II

thermal characteristics

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{ extsf{ heta}JC}$	Junction to case thermal resistance		N.100	1.56	°C/W
	WWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWWW	IN WI	11	01.0	M.

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

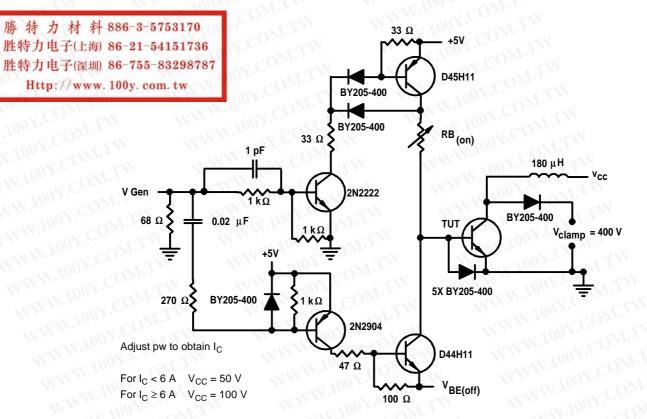
	PARAMETER	WT.	TEST CONDITION	s t	MIN	TYP	MAX	UNIT
t _{sv}	Voltage storage time	I _C = 3 A V _{BE(off)} = -5 V	I _{B(on)} = 0.6 A	(see Figures 1 and 2)	<	WW	2.5	μs
t _{rv}	Voltage rise time					IN	300	ns
t _{fi}	Current fall time					M.	250	ns
t _{ti}	Current tail time					WW	150	ns
t _{xo}	Cross over time						400	ns
t _{sv}	Voltage storage time	N.C.	I _{B(on)} = 0.6 A T _C = 100°C	(see Figures 1 and 2)		N.	3	μs
t _{rv}	Voltage rise time				N	N/	500	ns
t _{fi}	Current fall time	I _C = 3 A V _{BE(off)} = -5 V					250	ns
t _{ti}	Current tail time	$V_{BE(off)} = -5 V$			1		150	ns
t _{xo}	Cross over time						750	ns

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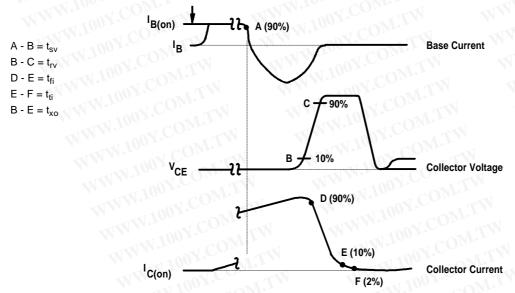
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PARAMETER MEASUREMENT INFORMATION

Figure 1. Inductive-Load Switching Test Circuit

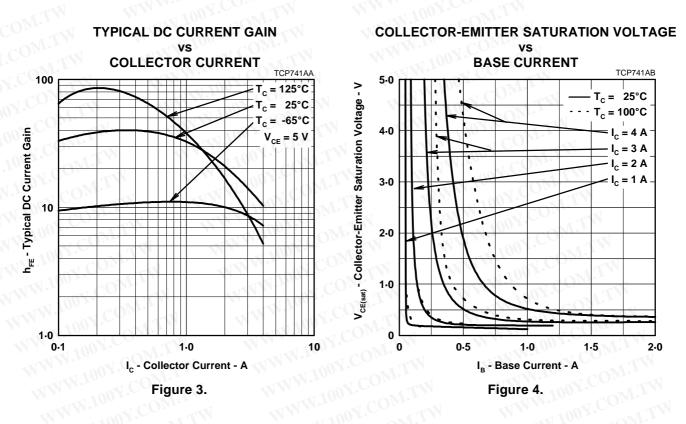


NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics: t_r < 15 ns, R_{in} > 10 Ω, C_{in} < 11.5 pF. B. Resistors must be noninductive types.

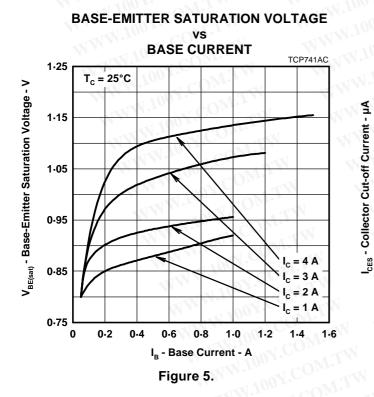
Figure 2. Inductive-Load Switching Waveforms

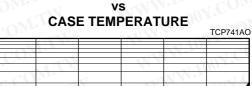
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TYPICAL CHARACTERISTICS





COLLECTOR CUT-OFF CURRENT

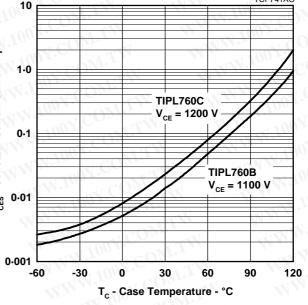


Figure 6.



PRODUCT INFORMATION

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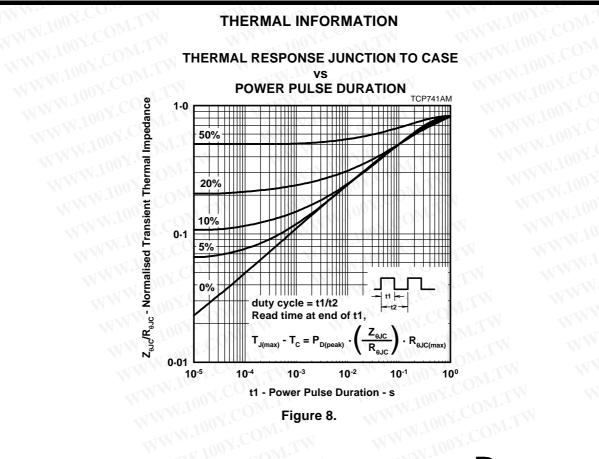
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WWW.100Y.COM **MAXIMUM FORWARD-BIAS** SAFE OPERATING AREA SAP741AF 1. I_c - Collector Current - A .0 10 µs t_p = 100 µs t_n = 1 ms t, ÷ 10 ms t. = TIPL760B **DC** Operation TIPL760C 0.01 1.0 10 100 1000 V_{CE} - Collector-Emitter Voltage - V Figure 7.

THERMAL INFORMATION





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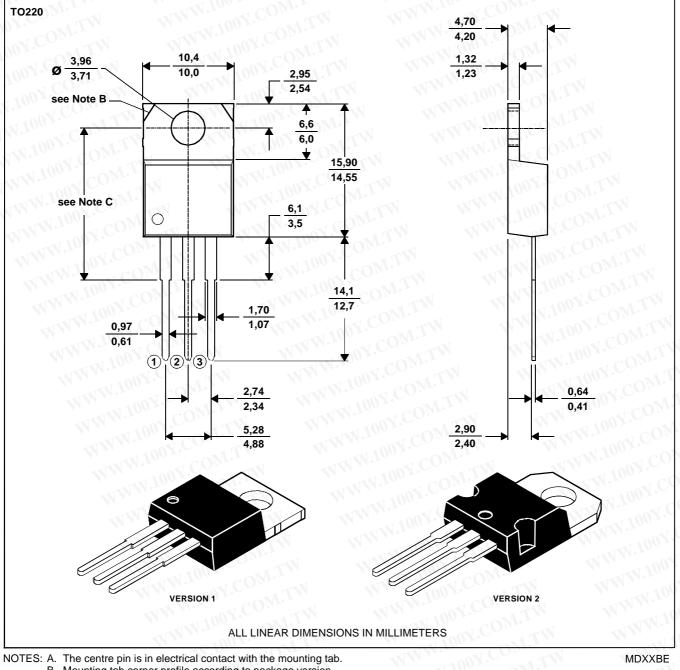
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

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